

TOSHIBA Transistor Silicon NPN Epitaxial Type

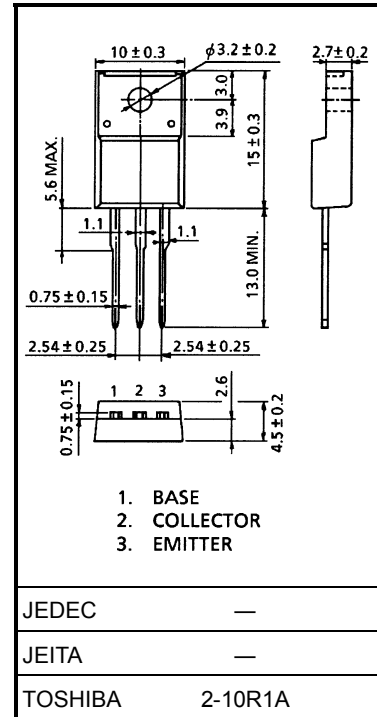
2SC4881

High-Current Switching Applications

- Low saturation voltage: $V_{CE(sat)} = 0.4 \text{ V (max)}$
- High-speed switching: $t_{stg} = 0.8 \mu\text{s (typ.)}$

Maximum Ratings ($T_c = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	60	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	DC	I_C	5
	Pulse	I_{CP}	8
Base current	I_B	1	A
Collector power dissipation	$T_a = 25^\circ\text{C}$	P_C	2.0
	$T_c = 25^\circ\text{C}$		20
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$



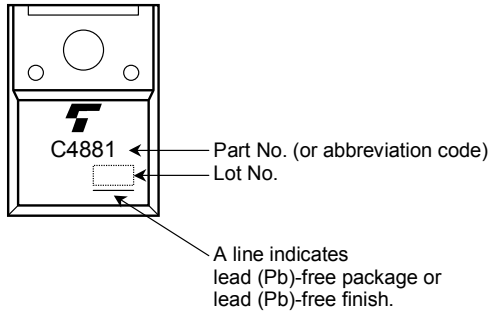
Electrical Characteristics ($T_c = 25^\circ\text{C}$)

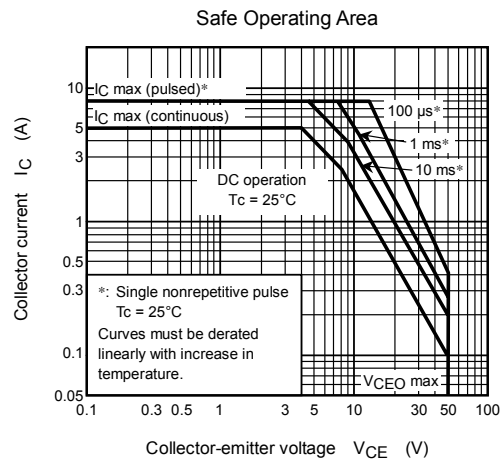
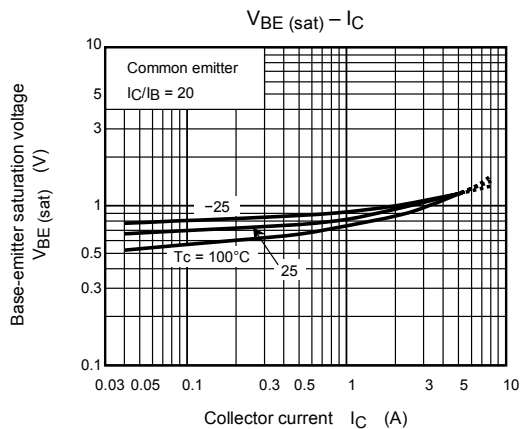
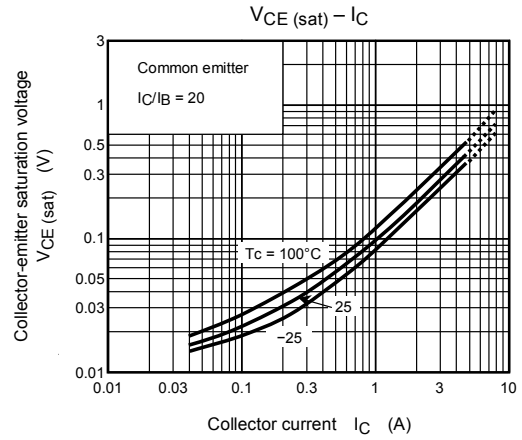
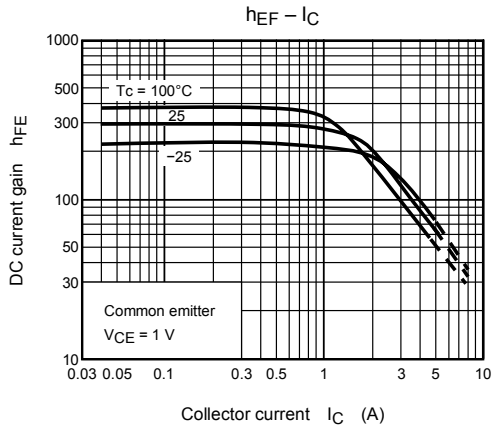
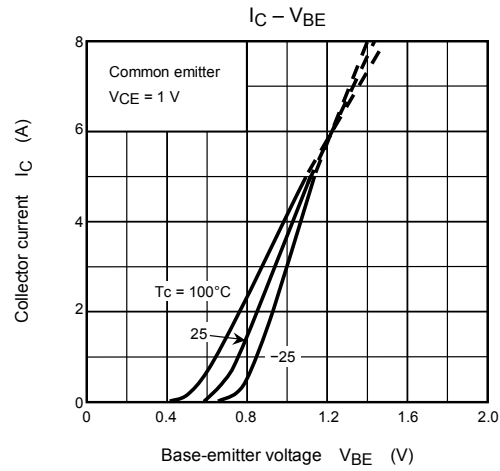
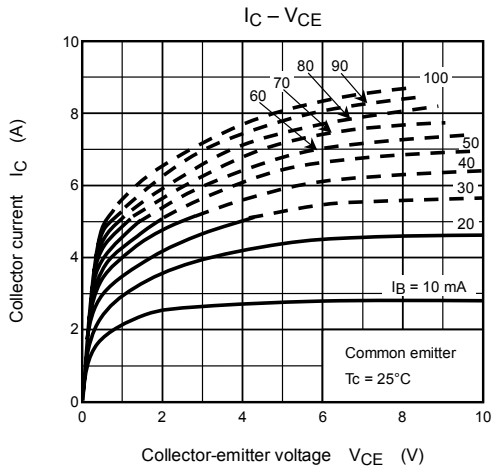
Weight: 1.7 g (typ.)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$	—	—	1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$	—	—	1	μA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 10 \text{ mA}, I_B = 0$	50	—	—	V
DC current gain	$h_{FE(1)}$	$V_{CE} = 1 \text{ V}, I_C = 1 \text{ A}$	100	—	320	
	$h_{FE(2)}$	$V_{CE} = 1 \text{ V}, I_C = 2.5 \text{ A}$	60	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 2.5 \text{ A}, I_B = 125 \text{ mA}$	—	0.25	0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 2.5 \text{ A}, I_B = 125 \text{ mA}$	—	1.0	1.3	V
Transition frequency	f_T	$V_{CB} = 4 \text{ V}, I_C = 1 \text{ A}$	—	100	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	—	45	—	pF
Switching time	Turn-on time	t_{on}	—	0.1	—	μs
	Storage time	t_{stg}	—	0.8	—	
	Fall time	t_f	—	0.1	—	

$I_{B1} = -I_{B2} = 125 \text{ mA}, \text{ duty cycle } \leq 1\%$

Marking





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